RENESAS 8-Output Very Low-Power PCIe Gen 1–4 Clock Generator

9FGV0831

DATASHEET

Description

The 9FGV0831 is a member of IDT's SOC-friendly 1.8V very low-power PCIe clock family. The device has 8 output enables for clock management, 2 different spread spectrum levels in addition to spread off, and 2 selectable SMBus addresses.

Recommended Application

PCIe Gen1–4 clock generation for Riser Cards, Storage, Networking, JBOD, Communications, Access Points

Output Features

- 8 100MHz Low-Power (LP) HCSL DIF pair
- 1 1.8V LVCMOS REF output with Wake-On-LAN (WOL) support

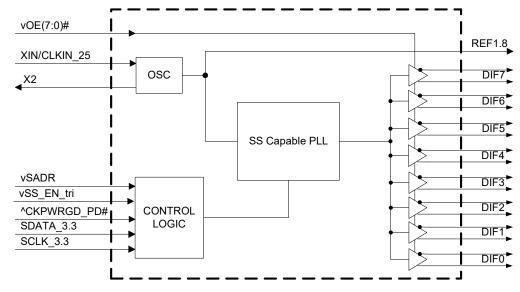
Key Specifications

- DIF cycle-to-cycle jitter <50ps
- DIF output-to-output skew <50ps
- DIF phase jitter is PCIe Gen1-2-3-4 compliant
- REF phase jitter is <1.5ps RMS

Features/Benefits

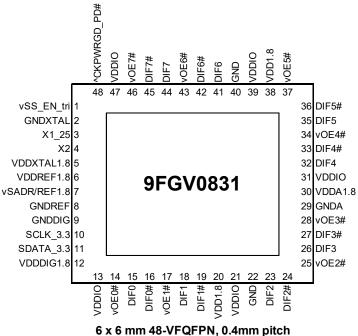
- LP-HCSL outputs; saves 16 resistors compared to standard PCIe devices
- 62mW typical power consumption; reduced thermal concerns
- Outputs can optionally be supplied from any voltage between 1.05 and 1.8V; maximum power savings
- OE# pins; support DIF power management
- Programmable slew rate for each output; allows tuning for various line lengths
- Programmable output amplitude; allows tuning for various application environments
- DIF outputs blocked until PLL is locked; clean system start-up
- Selectable 0%, -0.25% or -0.5% spread on DIF outputs; reduces EMI
- External 25MHz crystal; supports tight ppm with 0 ppm synthesis error
- Configuration can be accomplished with strapping pins; SMBus interface not required for device control
- 3.3V tolerant SMBus interface works with legacy controllers
- Selectable SMBus addresses; multiple devices can easily share an SMBus segment
- Space saving 6 x 6 mm 48-VFQFPN; minimal board space







Pin Configuration



vv prefix indicates internal 60kOhm pull-down resistor

v prefix indicates internal 120kOhm pull-down resistor

^ prefix indicates internal 120kOhm pull-up resistor

SMBus Address Selection Table

	SADR	Address	+ Read/Write Bit
State of SADR on first application	0	1101000	Х
of CKPWRGD_PD#	1	1101010	Х

Power Management Table

CKPWRGD PD# SMBus DIFx					REF
	OE bit	OEx#	True O/P	Comp. O/P	
0	Х	Х	Low	Low	Hi-Z ¹
1	1	0	Running	Running	Running
1	0	1	Low	Low	Low

1. REF is Hi-Z until the 1st assertion of CKPWRGD_PD# high. After this, when CKPWRG_PD# is low, REF is Low.

Power Connections

Pin Number			Description
VDD	VDDIO	GND	Description
5		2	XTAL OSC
6		8	REF Power
12		9	Digital (dirty) Power
20,38	13,21,31,39, 47	22,29,40	DIF outputs
30		29	PLL Analog

Pin Descriptions

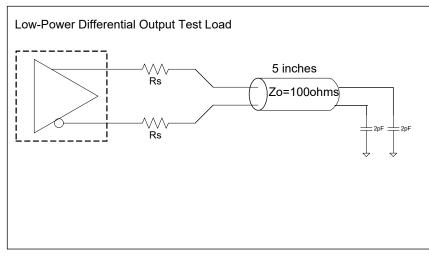
PIN #	PIN NAME	TYPE	DESCRIPTION
4		LATCHED	Latched select input to select spread spectrum amount at initial power up :
1	vSS_EN_tri	IN	1 = -0.5% spread, M = -0.25%, 0 = Spread Off
2	GNDXTAL	GND	GND for XTAL
3	X1 25	IN	Crystal input, Nominally 25.00MHz.
4	 X2	OUT	Crystal output.
5	VDDXTAL1.8	PWR	Power supply for XTAL, nominal 1.8V
6	VDDREF1.8	PWR	VDD for REF output. nominal 1.8V.
7	vSADR/REF1.8	LATCHED I/O	Latch to select SMBus Address/1.8V LVCMOS copy of X1/REFIN pin
8	GNDREF	GND	Ground pin for the REF outputs.
9	GNDDIG	GND	Ground pin for digital circuitry
10	SCLK 3.3	IN	Clock pin of SMBus circuitry, 3.3V tolerant.
11	SDATA 3.3	I/O	Data pin for SMBus circuitry, 3.3V tolerant.
12	VDDDIG1.8	PWR	1.8V digital power (dirty power)
13	VDDIO	PWR	Power supply for differential outputs
14	vOE0#	IN	Active low input for enabling DIF pair 0. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
15	DIF0	OUT	Differential true clock output
16	DIF0#	OUT	Differential Complementary clock output
17	vOE1#	IN	Active low input for enabling DIF pair 1. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
18	DIF1	OUT	Differential true clock output
19	DIF1#	OUT	Differential Complementary clock output
20	VDD1.8	PWR	Power supply, nominal 1.8V
21	VDDIO	PWR	Power supply for differential outputs
22	GND	GND	Ground pin.
23	DIF2	OUT	Differential true clock output
24	DIF2#	OUT	Differential Complementary clock output
25	vOE2#	IN	Active low input for enabling DIF pair 2. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
26	DIF3	OUT	Differential true clock output
27	DIF3#	OUT	Differential Complementary clock output
28	vOE3#	IN	Active low input for enabling DIF pair 3. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
29	GNDA	GND	Ground pin for the PLL core.
30	VDDA1.8	PWR	1.8V power for the PLL core.
31	VDDIO	PWR	Power supply for differential outputs
32	DIF4	OUT	Differential true clock output
33	DIF4#	OUT	Differential Complementary clock output
34	vOE4#	IN	Active low input for enabling DIF pair 4. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
35	DIF5	OUT	Differential true clock output
36	DIF5#	OUT	Differential Complementary clock output
37	vOE5#	IN	Active low input for enabling DIF pair 5. This pin has an internal pull-down. 1 =disable outputs, 0 = enable outputs
38	VDD1.8	PWR	Power supply, nominal 1.8V
39	VDDIO	PWR	Power supply for differential outputs



Pin Descriptions (cont.)

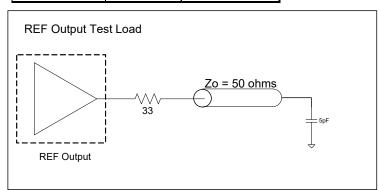
PIN #	PIN NAME	TYPE	DESCRIPTION			
40	GND	GND	Ground pin.			
41	DIF6	OUT	Differential true clock output			
42	DIF6#	OUT	Differential Complementary clock output			
43	vOE6#	IN	Active low input for enabling DIF pair 6. This pin has an internal pull-down.			
			1 =disable outputs, 0 = enable outputs			
44	DIF7	OUT	Differential true clock output			
45	DIF7#	OUT	Differential Complementary clock output			
46	vOE7#	IN	Active low input for enabling DIF pair 7. This pin has an internal pull-down.			
40	VOE7#	IIN	1 =disable outputs, 0 = enable outputs			
47	VDDIO	PWR	Power supply for differential outputs			
			Input notifies device to sample latched inputs and start up on first high			
48	^CKPWRGD_PD#	IN	assertion. Low enters Power Down Mode, subsequent high assertions exit			
			Power Down Mode. This pin has internal pull-up resistor.			

Test Loads

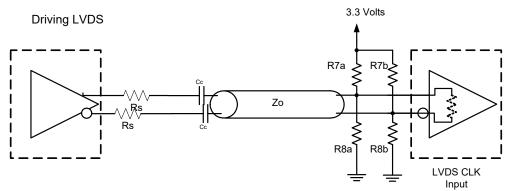


Alternate Differential Output Terminations

Rs	Zo	Units
33	100	Ohms
27	85	Onins



Alternate Terminations



Driving LVDS inputs

	`	Value		
	Receiver has Receiver does not			
Component	termination	have termination	Note	
R7a, R7b	10K ohm	140 ohm		
R8a, R8b	5.6K ohm	75 ohm		
Сс	0.1 uF	0.1 uF		
Vcm	1.2 volts	1.2 volts		

Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the 9FGV0831. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Supply Voltage	VDDxx	Applies to all VDD pins	-0.5		2.5	V	1,2
Input Voltage	V _{IN}		-0.5		V_{DD} +0.5V	V	1, 3
Input High Voltage, SMBus	VIHSMB	SMBus clock and data pins			3.6V	V	1
Storage Temperature	Ts		-65		150	°C	1
Junction Temperature	Tj				125	°C	1
Input ESD protection	ESD prot	Human Body Model	2000			V	1

¹Guaranteed by design and characterization, not 100% tested in production.

² Operation under these conditions is neither implied nor guaranteed.

³ Not to exceed 2.5V.

Electrical Characteristics–Current Consumption

TA = T_{AMB;} Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
	I _{DDAOP}	VDDA, All outputs active @100MHz		6	9	mA	
Operating Supply Current	I _{DDOP}	All VDD, except VDDA and VDDIO, All outputs active @100MHz		12	15	mA	
	IDDIOOP	VDDIO, All outputs active @100MHz		28	36	mA	
Wake-on-LAN Current	I _{DDAPD}	VDDA, DIF outputs off, REF output running		0.4	1	mA	2
(CKPWRGD_PD# = '0' Byte 3, bit 5 = '1')	I _{DDPD}	All VDD, except VDDA and VDDIO, DIF outputs off, REF output running		5.5	9	mA	2
Dyte 3, bit 5 = 1)	IDDIOPD	VDDIO, DIF outputs off, REF output running		0.04	0.1	mA	2
Powerdown Current	I _{DDAPD}	VDDA, all outputs off		0.4	1	mA	
(CKPWRGD_PD# = '0'	I _{DDPD}	All VDD, except VDDA and VDDIO, all outputs off		0.6	1	mA	
Byte 3, bit 5 = '0')	I _{DDIOPD}	VDDIO, all outputs off		0.0003	0.1	mA	

¹ Guaranteed by design and characterization, not 100% tested in production.

² This is the current required to have the REF output running in Wake-on-LAN mode (Byte 3, bit 5 = 1)

Electrical Characteristics–DIF Output Duty Cycle, Jitter, and Skew Characteristics

TA = T_{AMB:} Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Duty Cycle	t _{DC}	Measured differentially, PLL Mode	45	49.9	55	%	1,2
Skew, Output to Output	t _{sk3}	Averaging on, $V_T = 50\%$		37	50	ps	1,2
Jitter, Cycle to cycle	t _{jcyc-cyc}			12	50	ps	1,2

6

¹Guaranteed by design and characterization, not 100% tested in production.

² Measured from differential waveform

Electrical Characteristics–Input/Supply/Common Parameters–Normal Operating Conditions

	was services and a service service and the service	See Test Loads for Loading Conditions
IA = Live Supply Voltages	per normal operation conditions	See lest loads for Loading Conditions
	per normal operation conditione,	Cool root Educe for Educing Conditions

PARAMETER	SYMBOL		MIN	TYP	MAX	UNITS	NOTES
Supply Voltage	VDDxx	Supply voltage for core, analog and single-ended LVCMOS outputs	1.7	1.8	1.9	V	
Output Supply Voltage	VDDIO	Supply voltage for differential Low Power Outputs	0.9975	1.05-1.8	1.9	V	
Ambient Operating	T _{AMB}	Commercial range	0	25	70		
Temperature		Industrial range	-40	25	85		
Input High Voltage	V _{IH}	Single-ended inputs, except SMBus	$0.75 V_{DD}$		V _{DD} + 0.3		
Input Mid Voltage	V _{IM}	Single-ended tri-level inputs ('_tri' suffix)	0.4 V _{DD}	$0.5 V_{DD}$	0.6 V _{DD}		
Input Low Voltage	V _{IL}	Single-ended inputs, except SMBus	-0.3		$0.25 \ V_{DD}$		
Output High Voltage	V _{IH}	Single-ended outputs, except SMBus. I _{OH} = -2mA	V _{DD} -0.45			V	
Output Low Voltage	V _{IL}	Single-ended outputs, except SMBus. I _{OL} = -2mA			0.45	V	
	I _{IN}	Single-ended inputs, V_{IN} = GND, V_{IN} = VDD	-5		5	uA	
Input Current	I _{INP}	Single-ended inputs V_{IN} = 0 V; Inputs with internal pull-up resistors V_{IN} = VDD; Inputs with internal pull-down resistors	-20		20	uA	
Input Frequency	F _{in}	XTAL, or X1 input	23	25	27	MHz	
Pin Inductance	L _{pin}				7	nH	1
Conseitence	C _{IN}	Logic Inputs, except DIF_IN	1.5		5	pF	1
Capacitance	C _{OUT}	Output pin capacitance			6	V °C °C V V V V V uA uA uA	1
Clk Stabilization	T _{STAB}	From V _{DD} Power-Up and after input clock stabilization or de-assertion of PD# to 1st clock		0.6	1.8	ms	1,2
SS Modulation Frequency	f _{MOD}	Allowable Frequency (Triangular Modulation)	30	31.6	33	kHz	1
OE# Latency	t _{LATOE#}	DIF start after OE# assertion DIF stop after OE# deassertion	1	3	3	clocks	1,3
Tdrive_PD#	t _{DRVPD}	DIF output enable after PD# de-assertion		20	300	us	1,3
Tfall	t _F	Fall time of single-ended control inputs			5	ns	2
Trise	t _R	Rise time of single-ended control inputs			5	ns	2
SMBus Input Low Voltage	VILSMB	V_{DDSMB} = 3.3V, see note 4 for V_{DDSMB} < 3.3V			0.6		
SMBus Input High Voltage	VIHSMB	V_{DDSMB} = 3.3V, see note 5 for V_{DDSMB} < 3.3V	2.1		3.6		4
SMBus Output Low Voltage	V _{OLSMB}	@ I _{PULLUP}			0.4	V	
SMBus Sink Current	I _{PULLUP}	@ V _{OL}	4			mA	
Nominal Bus Voltage	V _{DDSMB}		1.7		3.6	V	
SCLK/SDATA Rise Time	t _{RSMB}	(Max VIL - 0.15) to (Min VIH + 0.15)			1000	ns	1
SCLK/SDATA Fall Time	t _{FSMB}	(Min VIH + 0.15) to (Max VIL - 0.15)			300	ns	1
SMBus Operating Frequency	f _{MAXSMB}	Maximum SMBus operating frequency			400	kHz	1

¹ Guaranteed by design and characterization, not 100% tested in production.

² Control input must be monotonic from 20% to 80% of input swing.

 3 Time from deassertion until outputs are > 200mV.

 4 For V_{DDSMB} < 3.3V, V_{IHSMB} >= 0.65xV_{DDSMB}.

7

Electrical Characteristics–DIF Low Power HCSL Outputs

TA = T_{AMB}; Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

AND, IT J J	· ·						
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Slew rate	Trf	Scope averaging on fast setting	1.8	2.7	4.4	V/ns	1,2,3
Slew late	111	Scope averaging on slow setting	1.4	2.1	3.4	V/ns	1,2,3
Slew rate matching	∆Trf	Slew rate matching, Scope averaging on		4	20	%	1,2,4
Voltage High	V _{HIGH}	Statistical measurement on single-ended signal using oscilloscope math function. (Scope		793	850	mV	7
Voltage Low	V _{LOW}	averaging on)	-150	16	150	IIIV	7
Max Voltage	Vmax	Measurement on single ended signal using		831	1150	mV	7
Min Voltage	Vmin	absolute value. (Scope averaging off)	-300	-95		IIIV	7
Vswing	Vswing	Scope averaging off	300	1555		mV	1,2,7
Crossing Voltage (abs)	Vcross_abs	Scope averaging off	250	429	550	mV	1,5,7
Crossing Voltage (var)	∆-Vcross	Scope averaging off		12	140	mV	1,6,7

¹Guaranteed by design and characterization, not 100% tested in production.

² Measured from differential waveform

³ Slew rate is measured through the Vswing voltage range centered around differential 0V. This results in a +/-150mV window around differential 0V.

⁴ Matching applies to rising edge rate for Clock and falling edge rate for Clock#. It is measured using a +/-75mV window centered on the average cross point where Clock rising meets Clock# falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations.

⁵ Vcross is defined as voltage where Clock = Clock# measured on a component test board and only applies to the differential rising edge (i.e. Clock rising and Clock# falling).

⁶ The total variation of all Vcross measurements in any particular system. Note that this is a subset of Vcross_min/max (Vcross absolute) allowed. The intent is to limit Vcross induced modulation by setting Δ-Vcross to be smaller than Vcross absolute.

⁷ At default SMBus amplitude settings.

Electrical Characteristics–Filtered Phase Jitter Parameters - PCIe Common Clocked (CC) Architectures

T_{AMB} = over the specified operating range. Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	Specification Limit	UNITS	NOTES
t _{jphPCleG1-CC}		PCIe Gen 1	21	25	35	86	ps (p-p)	1, 2, 3
t		PCIe Gen 2 Low Band 0.9 10kHz < f < 1.5MHz		1.1	3	ps (rms)	1, 2	
ljphPCleG2-CC		PCIe Gen 2 High Band 1.5MHz < f < Nyquist (50MHz) (PLL BW of 5-16MHz, 8-16MHz, CDR = 5MHz)	1.5	1.6	1.9	3.1	ps (rms)	1, 2
t _{jphPCleG3-CC}		PCIe Gen 3 (PLL BW of 2-4MHz, 2-5MHz, CDR = 10MHz)	0.3	0.37	0.44	1	ps (rms)	1, 2
t _{jphPCleG4-CC}		PCIe Gen 4 (PLL BW of 2-4MHz, 2-5MHz, CDR = 10MHz)	0.3	0.37	0.44	0.5	ps (rms)	1, 2

Notes on PCIe Filtered Phase Jitter Table

¹ Applies to all differential outputs, guaranteed by design and characterization.

² Calculated from Intel-supplied Clock Jitter Tool, with spread on and off.

³ Sample size of at least 100K cycles. This figure extrapolates to 108ps pk-pk at 1M cycles for a BER of 1⁻¹².

Electrical Characteristics-REF

TA = T_{AMB;} Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	Notes
Long Accuracy	ppm	see Tperiod min-max values		0		ppm	1,2
Clock period	T _{period}	25 MHz output		40		ns	2
Rise/Fall Slew Rate	t _{rf1}	Byte 3 = 1F, 20% to 80% of VDDREF	0.6	1	1.6	V/ns	1
Rise/Fall Slew Rate	t _{rf1}	Byte 3 = 5F, 20% to 80% of VDDREF	0.9	1.4	2.2	V/ns	1,3
Rise/Fall Slew Rate	t _{rf1}	Byte 3 = 9F, 20% to 80% of VDDREF	1.1	1.7	2.7	V/ns	1
Rise/Fall Slew Rate	t _{rf1}	Byte 3 = DF, 20% to 80% of VDDREF	1.1	1.8	2.9	V/ns	1
Duty Cycle	d _{t1X}	V _T = VDD/2 V	45	49.1	55	%	1,4
Duty Cycle Distortion	d _{tcd}	$V_T = VDD/2 V$	0	2	4	%	1,5
Jitter, cycle to cycle	t _{jcyc-cyc}	$V_T = VDD/2 V$		19.1	250	ps	1,4
Noise floor	t _{jdBc1k}	1kHz offset		-129.8	-105	dBc	1,4
Noise floor	t _{jdBc10k}	10kHz offset to Nyquist		-143.6	-115	dBc	1,4
Jitter, phase	t _{jphREF}	12kHz to 5MHz		0.63	1.5	ps (rms)	1,4

¹Guaranteed by design and characterization, not 100% tested in production.

² All Long Term Accuracy and Clock Period specifications are guaranteed assuming that REF is trimmed to 25.00 MHz

³ Default SMBus Value

⁴ When driven by a crystal.

⁵ When driven by an external oscillator via the X1 pin, X2 should be floating.

Clock Periods–Differential Outputs with Spread Spectrum Disabled

			Measurement Window							
	Center	1 Clock	1us	0.1s	0.1s	0.1s	1us	1 Clock		
SSC OFF	Freq. MHz	-c2c jitter AbsPer Min	-SSC Short-Term Average Min	- ppm Long-Term Average Min	0 ppm Period Nominal	+ ppm Long-Term Average Max	+SSC Short-Term Average Max	+c2c jitter AbsPer Max	Units	Notes
DIF	100.00	9.94900		9.99900	10.00000	10.00100		10.05100	ns	1,2

Clock Periods–Differential Outputs with Spread Spectrum Enabled

				Me	easurement W	indow	Measurement Window							
	Center	1 Clock	1us	0.1s	0.1s	0.1s	1us	1 Clock	Ι					
SSC ON	Freq. MHz	-c2c jitter AbsPer Min	-SSC Short-Term Average Min	- ppm Long-Term Average Min	0 ppm Period Nominal	+ ppm Long-Term Average Max	+SSC Short-Term Average Max	+c2c jitter AbsPer Max	Units	Notes				
DIF	99.75	9.94906	9.99906	10.02406	10.02506	10.02607	10.05107	10.10107	ns	1,2				

¹Guaranteed by design and characterization, not 100% tested in production.

² All Long Term Accuracy and Clock Period specifications are guaranteed assuming that REF is trimmed to 25.00 MHz

9

General SMBus Serial Interface Information

How to Write

- Controller (host) sends a start bit
- Controller (host) sends the write address
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- Controller (host) sends the byte count = X
- IDT clock will acknowledge
- Controller (host) starts sending Byte N through Byte N+X-1
- IDT clock will acknowledge each byte one at a time
- Controller (host) sends a stop bit

	Index Blo	ock \	Write Operation
Controll	er (Host)		IDT (Slave/Receiver)
Т	starT bit		
Slave A	Address		
WR	WRite		
			ACK
Beginning	g Byte = N		
			ACK
Data Byte	Count = X		
			ACK
Beginnir	ng Byte N		
			ACK
0		×	
0		X Byte	0
0		ē	0
			0
Byte N	+ X - 1		
			ACK
Р	stoP bit		

Note: SMBus address is latched on SADR pin.

How to Read

- Controller (host) will send a start bit
- Controller (host) sends the write address
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- Controller (host) will send a separate start bit
- Controller (host) sends the read address
- IDT clock will acknowledge
- IDT clock will send the data byte count = X
- IDT clock sends Byte N+X-1
- IDT clock sends Byte 0 through Byte X (if X_(H) was written to Byte 8)
- Controller (host) will need to acknowledge each byte
- Controller (host) will send a not acknowledge bit
- Controller (host) will send a stop bit

	Index Block F	Read C	Operation
Co	ontroller (Host)		IDT (Slave/Receiver)
Т	starT bit		
S	lave Address		
WR	WRite		
		_	ACK
Beg	inning Byte = N	_	
		_	ACK
RT	Repeat starT	_	
S	lave Address		
RD	ReaD		
			ACK
			Data Byte Count=X
	ACK		
		_	Beginning Byte N
	ACK		
		e	0
	0	X Byte	0
	0	×	0
	0		
	1		Byte N + X - 1
Ν	Not acknowledge		
Р	stoP bit		

SMBus Table: Output Enable Register ¹

Byte 0	Name	Control Function	Туре	0	1	Default
Bit 7	DIF OE7	Output Enable	RW	Low/Low	Enabled	1
Bit 6	DIF OE6	Output Enable	RW	Low/Low	Enabled	1
Bit 5	DIF OE5	Output Enable	RW	Low/Low	Enabled	1
Bit 4	DIF OE4	Output Enable	RW	Low/Low	Enabled	1
Bit 3	DIF OE3	Output Enable	RW	Low/Low	Enabled	1
Bit 2	DIF OE2	Output Enable	RW	Low/Low	Enabled	1
Bit 1	DIF OE1	Output Enable	RW	Low/Low	Enabled	1
Bit 0	DIF OE0	Output Enable	RW	Low/Low	Enabled	1

1. A low on these bits will override the OE# pin and force the differential output Low/Low

SMBus Table: SS Readback and Control Register

Byte 1	Name	Control Function	Туре	0	1	Default
Bit 7	SSENRB1	SS Enable Readback Bit1	R	00' for SS_EN_tri =	0, '01' for SS_EN_tri	Latch
Bit 6	SSENRB1	SS Enable Readback Bit0	R	= 'M', '11 for S	S_EN_tri = '1'	Latch
Bit 5	SSEN_SWCNTRL	Enable SW control of SS	RW		Values in B1[4:3] control SS amount.	0
Bit 4	SSENSW1	SS Enable Software Ctl Bit1	RW ¹	00' = SS Off, '0'	1' = -0.25% SS,	0
Bit 3	SSENSW0	SS Enable Software Ctl Bit0	RW ¹	'10' = Reserved	, '11'= -0.5% SS	0
Bit 2		Reserved				1
Bit 1	AMPLITUDE 1	Controls Output Amplitude	RW	00 = 0.6V	01 = 0.7V	1
Bit 0	AMPLITUDE 0		RW	10= 0.8V	11 = 0.9V	0

1. B1[5] must be set to a 1 for these bits to have any effect on the part.

SMBus Table: DIF Slew Rate Control Register

Byte 2	Name	Control Function	Туре	0	1	Default
Bit 7	SLEWRATESEL DIF7	Adjust Slew Rate of DIF7	RW	Slow Setting	Fast Setting	1
Bit 6	SLEWRATESEL DIF6	Adjust Slew Rate of DIF6	RW	Slow Setting	Fast Setting	1
Bit 5	SLEWRATESEL DIF5	Adjust Slew Rate of DIF5	RW	Slow Setting	Fast Setting	1
Bit 4	SLEWRATESEL DIF4	Adjust Slew Rate of DIF4	RW	Slow Setting	Fast Setting	1
Bit 3	SLEWRATESEL DIF3	Adjust Slew Rate of DIF3	RW	Slow Setting	Fast Setting	1
Bit 2	SLEWRATESEL DIF2	Adjust Slew Rate of DIF2	RW	Slow Setting	Fast Setting	1
Bit 1	SLEWRATESEL DIF1	Adjust Slew Rate of DIF1	RW	Slow Setting	Fast Setting	1
Bit 0	SLEWRATESEL DIF0	Adjust Slew Rate of DIF0	RW	Slow Setting	Fast Setting	1

SMBus Table: Nominal Vhigh Amplitude Control/ REF Control Register

Byte 3	Name	Control Function	Туре	0	1	Default
Bit 7	REF	Slew Rate Control	RW	00 = Slowest	01 = Slow	0
Bit 6	INE!			10 = Fast	11 = Faster	1
Bit 5 REF Power Down Function		Wake-on-Lan Enable for REF	RW	REF does not run in	REF runs in Power	0
DIUS			1.00	Power Down	Down	0
Bit 4	REF OE	REF Output Enable		Low	Enabled	1
Bit 3		Reserved				1
Bit 2	Reserved					
Bit 1	Reserved					
Bit 0		Reserved				1

Byte 4 is Reserved

RENESAS 9FGV0831 DATASHEET

SMBus Table: Revision and Vendor ID Register

Byte 5	Name	Control Function	Туре	0	1	Default
Bit 7	RID3		R		-	0
Bit 6	RID2	Revision ID	R	C rev:	0	
Bit 5	RID1	Revision ID	R	C IEV	0	
Bit 4	RID0		R		1	
Bit 3	VID3		R			0
Bit 2	VID2	VENDOR ID	R	0001 = IDT		0
Bit 1	VID1	VENDOR ID	R			0
Bit 0	VID0]	R		1	

SMBus Table: Device Type/Device ID

Byte 6	Name	Control Function	Туре	0	1	Default
Bit 7	Device Type1	Device Type	R	00 = FGx, 01 = DBx ZDB/FOB,		0
Bit 6	Device Type0	Device Type		10 = DMx, 1	1= DBx FOB	0
Bit 5	Device ID5		R			0
Bit 4	Device ID4		R			0
Bit 3	Device ID3	Device ID	R	001000 bina	n/ or 08 bey	1
Bit 2	Device ID2	Device ID	R	001000 0111a	IY OF UO HEX	0
Bit 1	Device ID1		R			0
Bit 0	Device ID0		R			0

SMBus Table: Byte Count Register

Byte 7	Name	Control Function	Туре	0	1	Default
Bit 7	it 7 Reserved					0
Bit 6	Reserved				0	
Bit 5	Reserved				0	
Bit 4	BC4		RW			0
Bit 3	BC3		RW	Writing to this regist	er will configure how	1
Bit 2	BC2	Byte Count Programming	RW	many bytes will be r	ead back, default is	0
Bit 1	BC1		RW	= 8 b	ytes.	0
Bit 0	BC0		RW			0

12

Recommended Crystal Characteristics (3225 package)

PARAMETER	VALUE	UNITS	NOTES
Frequency	25	MHz	1
Resonance Mode	Fundamental	-	1
Frequency Tolerance @ 25°C	<u>+</u> 20	PPM Max	1
Frequency Stability, ref @ 25°C Over Operating Temperature Range	±20	PPM Max	1
Temperature Range (commercial)	0~70	°C	1
Temperature Range (industrial)	-40~85	°C	2
Equivalent Series Resistance (ESR)	50	Ω Max	1
Shunt Capacitance (C _O)	7	pF Max	1
Load Capacitance (C _L)	8	pF Max	1
Drive Level	0.3	mW Max	1
Aging per year	±5	PPM Max	1

Notes:

1. FOX 603-25-150.

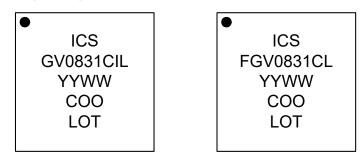
2. For I-temp, FOX 603-25-261.

Thermal Characteristics

PARAMETER	SYMBOL	CONDITIONS	PKG	TYP.	UNITS	NOTES
	θ _{JC}	Junction to Case		33	°C/W	1
	θ_{Jb}	Junction to Base		2.1	°C/W	1
Thermal Resistance	θ _{JA0}	Junction to Air, still air	NDG48	37	°C/W	1
memai Resistance	θ _{JA1}	Junction to Air, 1 m/s air flow	NDG40	30	°C/W	1
	θ_{JA3}	Junction to Air, 3 m/s air flow		27	°C/W	1
	θ_{JA5}	Junction to Air, 5 m/s air flow		26	°C/W	1

¹ePad soldered to board

Marking Diagrams



Notes:

1. Line 2 is the truncated part number.

2. "L" denotes RoHS compliant package.

3. "I" denotes industrial temperature grade.

4. "YYWW" is the last two digits of the year and week that the part was assembled.

13

5. "COO" denotes country of origin.

6. "LOT" is the lot number.

Package Outline Drawings

The package outline drawings are appended at the end of this document and are accessible from the link below. The package information is the most current data available.

www.idt.com/document/psc/48-vfqfpn-package-outline-drawing-60-x-60-x-090-mm-body-epad-41-x-41-mm-040mm-pitch-ndg48p1

Ordering Information

Part / Order Number	Shipping Packaging	Package	Temperature
9FGV0831CKLF	Trays	48-pin VFQFPN	0 to +70° C
9FGV0831CKLFT	Tape and Reel	48-pin VFQFPN	0 to +70° C
9FGV0831CKILF	Trays	48-pin VFQFPN	-40 to +85° C
9FGV0831CKILFT	Tape and Reel	48-pin VFQFPN	-40 to +85° C

"LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

"C" is the device revision designator (will not correlate with the datasheet revision).

Revision History

Revision Date	Description
	1. Updated front page text and block diagram.
	2. Updated pin out to remove references to VDD Suspend pins. Using the part with collapsible
September 29, 2014	power supplies did not save power and complicated board design. NO pins were changed.
September 29, 2014	3. Updated SMBus Descriptions
	4. Simplified footnote 2 on PPM table.
	5. Updated all electrical tables to latest format.
November 25, 2015	1. Updated POD with latest document
October 18, 2016	Removed IDT crystal part number
	1. Updated front page Gendes to reflect the PCIe Gen4 updates.
June 26, 2017	2. Updated Electrical Characteristics - Filtered Phase Jitter Parameters - PCle Common Clocked
	(CC) Architectures and added PCle Gen4 Data
May 13, 2019	Updated package outline drawings.
June 6, 2019	Changed Input Current minimum and maximum values from -200/200uA to -20/20uA.



IMPORTANT NOTICE AND DISCLAIMER

RENESAS ELECTRONICS CORPORATION AND ITS SUBSIDIARIES ("RENESAS") PROVIDES TECHNICAL SPECIFICATIONS AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS OR IMPLIED, INCLUDING, WITHOUT LIMITATION, ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, OR NON-INFRINGEMENT OF THIRD-PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for developers who are designing with Renesas products. You are solely responsible for (1) selecting the appropriate products for your application, (2) designing, validating, and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. Renesas grants you permission to use these resources only to develop an application that uses Renesas products. Other reproduction or use of these resources is strictly prohibited. No license is granted to any other Renesas intellectual property or to any third-party intellectual property. Renesas disclaims responsibility for, and you will fully indemnify Renesas and its representatives against, any claims, damages, costs, losses, or liabilities arising from your use of these resources. Renesas' products are provided only subject to Renesas' Terms and Conditions of Sale or other applicable terms agreed to in writing. No use of any Renesas resources expands or otherwise alters any applicable warranties or warranty disclaimers for these products.

(Disclaimer Rev.1.01)

Corporate Headquarters

TOYOSU FORESIA, 3-2-24 Toyosu, Koto-ku, Tokyo 135-0061, Japan www.renesas.com

Trademarks

Renesas and the Renesas logo are trademarks of Renesas Electronics Corporation. All trademarks and registered trademarks are the property of their respective owners.

Contact Information

For further information on a product, technology, the most up-to-date version of a document, or your nearest sales office, please visit <u>www.renesas.com/contact-us/</u>.